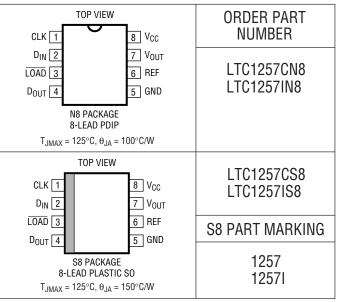
## **ABSOLUTE MAXIMUM RATINGS**

(Note 1)
V <sub>CC</sub> to GND0.5V to 16.5V
TTL Input Voltage $-0.5V$ to V <sub>CC</sub> + 0.5V
$V_{OUT}$
REF
Operating Temperature Range
LTC1257C 0°C to 70°C
LTC1257I –40°C to 85°C
Maximum Junction Temperature
Plastic Package –65°C to 125°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec)

### PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

## **ELECTRICAL CHARACTERISTICS**

The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = T_{MIN}$  to  $T_{MAX}$ .  $V_{CC} = 4.75V$  to 15.75V, internal or external reference (2.475V  $\leq V_{REF} \leq V_{CC} - 2.7V$ ), unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
DAC	1						
	Resolution			12			Bits
DNL	Differential Nonlinearity	Guaranteed Monotonic (Note 4)				±0.5	LSB
INL	Integral Nonlinearity	LTC1257C (Note 4) LTC1257I (Note 4)	•			±3.5 ±4.0	LSB LSB
OFF	Offset Error	When Using Internal Reference, LTC1257C When Using Internal Reference, LTC1257I	•			±8 ±10	LSB LSB
		When Using External Reference, LTC1257C When Using External Reference, LTC1257I	•			±4 ±5	mV mV
OFF <sub>TC</sub>	Offset Error Tempco	When Using Internal Reference (Note 2) When Using External Reference (Note 2)	•		±0.02 ±15	±0.066 ±30	LSB/°C µV/°C
	Gain Error				0.5	±2	LSB
	Gain Error Tempco	(Note 2)			$\pm 0.01$	±0.02	LSB/°C
Reference	8						
	Reference Output Voltage	I <sub>REF</sub> = 0, LTC1257C I <sub>REF</sub> = 0, LTC1257I	•	2.028 2.018	2.048	2.068 2.078	V V
	Reference Output Tempco	I <sub>REF</sub> = 0			±0.06		LSB/°C
	Reference Line Regulation	I <sub>REF</sub> = 0, LTC1257C I <sub>REF</sub> = 0, LTC1257I	•			±0.4 ±0.7	LSB/V LSB/V
	Reference Load Regulation	$0 \le I_{REF} \le 100 \mu A$				±1	LSB
	Reference Input Range	$V_{CC} > V_{REF} + 2.7V$		2.475		12	V
	Reference Input Resistance			8	14	18	kΩ
	Reference Input Capacitance	(Note 2)			15		pF
	Short-Circuit Current	V <sub>REF</sub> Shorted to GND				90	mA



### **ELECTRICAL CHARACTERISTICS**

The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = T_{MIN}$  to  $T_{MAX}$ .  $V_{CC} = 4.75V$  to 15.75V, internal or external reference (2.475V  $\leq V_{REF} \leq V_{CC} - 2.7V$ ), unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Power Su	pply	1					
V <sub>CC</sub>	Positive Supply Voltage	For Specified Performance		4.75		15.75	V
I <sub>CC</sub>	Supply Current	$\begin{array}{l} 4.75V \leq V_{CC} \leq 5.25V \\ 4.75V \leq V_{CC} \leq 15.75V \end{array}$	•		350 800	600 1500	μΑ μΑ
Op Amp D	C Performance						
	Short-Circuit Current Low	V <sub>OUT</sub> Shorted to GND	•			60	mA
	Short-Circuit Current High	V <sub>OUT</sub> Shorted to V <sub>CC</sub>	•			60	mA
	Output Impedance to GND	Input Code = 0	•		250	500	Ω
AC Perfor	mance						
	Voltage Output Slew Rate	$5k\Omega$ in Parallel with 100pF		1.0			V/µs
	Voltage Output Settling Time	To $\pm 1/2$ LSB, 5k $\Omega$ in Parallel with 100pF, V <sub>CC</sub> = 4.75V	•			6	μs
	Digital Feedthrough	(Notes 2,3)			50		nV/s
Digital I/O	)						
V <sub>IH</sub>	Digital Input High Voltage		•	2.4			V
V <sub>IL</sub>	Digital Input Low Voltage		•			0.8	V
V <sub>OH</sub>	Digital Output High Voltage	$I_{OUT} = -1 \text{mA}, D_{OUT} \text{Only}$	•	V <sub>CC</sub> – 1			V
V <sub>OL</sub>	Digital Output Low Voltage	I <sub>OUT</sub> = 1mA, D <sub>OUT</sub> Only	•	0.4			V
I <sub>LEAK</sub>	Digital Input Leakage	$V_{IN} = GND$ to $V_{CC}$	•			±10	μA
CIN	Digital Input Capacitance	(Note 2)	•			10	pF
Switching	(Note 2)						
t1	D <sub>IN</sub> Valid to CLK Setup		•	100			ns
t2	D <sub>IN</sub> Valid to CLK Hold		•	25			ns
t3	CLK High Time		•	350			ns
t4	CLK Low Time		•	350			ns
t5	LOAD Pulse Width		•	150			ns
t6	LSB CLK to LOAD			0			ns
t7	LOAD High to CLK			0			ns
t8	D <sub>OUT</sub> Output Delay	C <sub>LOAD</sub> = 15pF		35		150	ns
f <sub>CLK</sub>	Maximum Clock Frequency					1.4	MHz

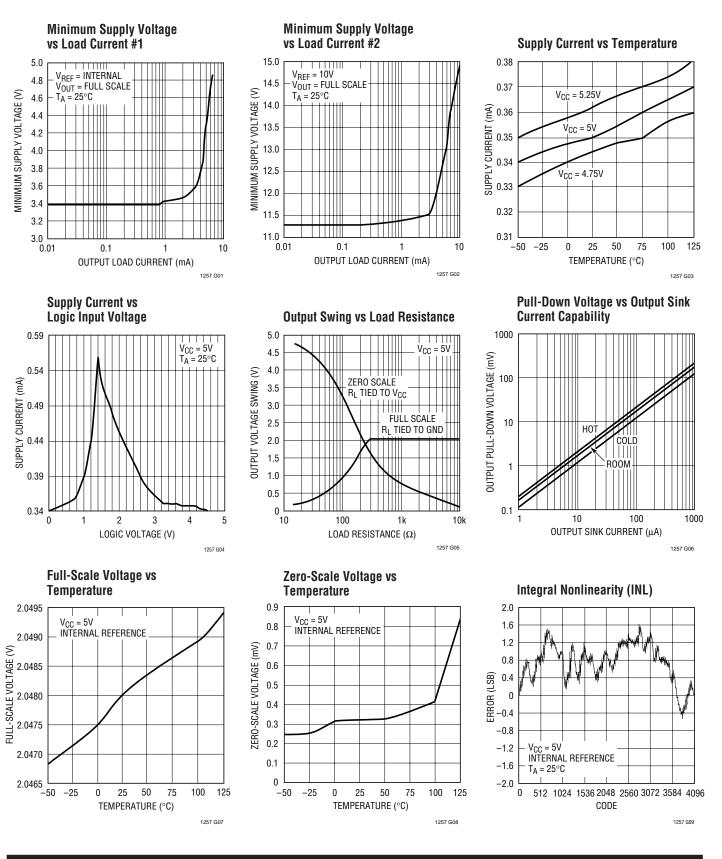
**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Guaranteed by design; not subject to test.

**Note 3:** DAC switched from all 1s to all 0s, and all 0s to all 1s code. **Note 4:** Guaranteed with internal  $V_{REF}$  or with external  $V_{REF}$  range of 2.475V to 12V. Tested at 10V.



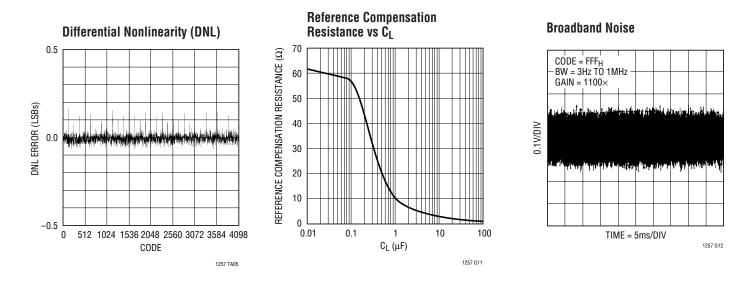
## TYPICAL PERFORMANCE CHARACTERISTICS





4 Downloaded from Arrow.com.

## TYPICAL PERFORMANCE CHARACTERISTICS



### **PIN FUNCTIONS**

**CLK (Pin 1):** The TTL level input for the serial interface clock.

 $D_{IN}$  (Pin 2): The TTL level input for the serial interface data. Data on the  $D_{IN}$  pin is latched into the shift register on the rising edge of the serial clock.

**LOAD** (Pin 3): The TTL level input for the serial interface load control. Data is loaded from the shift register into the DAC register, thus updating the DAC output when LOAD is pulled low. The DAC register is transparent as long as LOAD is held low.

 $D_{OUT}$ (Pin 4): The output of the shift register which becomes valid on the rising edge of the serial clock. The  $D_{OUT}$  pin is driven from GND to V<sub>CC</sub> by an internal CMOS inverter. Multiple LTC1257s may be cascaded by connecting the D<sub>OUT</sub> pin to the D<sub>IN</sub> pin of the next chip. GND (Pin 5): Ground.

**REF (Pin 6):** The output of the 2.048V reference and the input to the DAC resistor ladder. An external reference with voltage from 2.475V to  $V_{CC}$ -2.7V may be used to override the internal reference.

 $V_{OUT}$  (Pin 7): The buffered DAC output is capable of sourcing 2mA over temperature while pulling within 2.7V of V<sub>CC</sub>. The output will pull to ground through an internal 250 $\Omega$  equivalent resistance.

 $V_{CC}$  (Pin 8): The positive supply input. 4.75V  $\leq$  V\_{CC}  $\leq$  15.75V. Requires a bypass capacitor to ground.



## DEFINITIONS

**LSB:** The least significant bit or the ideal voltage difference between two successive codes.

 $LSB = (V_{FS} - V_{OS})/2^{n} - 1$ 

- n = The number of digital input bits
- $V_{OS}$  = The zero code error or offset of the DAC
- $V_{FS}$  = The full-scale output voltage of the DAC measured when all bits are set to 1

**Resolution:** The resolution is the number of DAC output states  $(2^n)$  that divide the full-scale range. The resolution does not imply linearity.

**INL:** End-point integral nonlinearity is the maximum deviation from a straight line passing through the end-points of the DAC transfer curve. Because the part operates from a single supply and the output cannot go below ground, the linearity is measured between full-scale and the first code that guarantees a positive output. The INL error at a given input code is calculated as follows:

 $INL = (V_{OUT} - V_{IDEAL})/LSB$ 

 $V_{IDEAL} = (Code)(LSB) + V_{OS}$ 

 $V_{OUT}$  = The output voltage of the DAC measured at the given input code

**DNL:** Differential nonlinearity is the difference between the measured change and the ideal 1LSB change between any two adjacent codes. The DNL error between any two codes is calculated as follows:

 $DNL = (\Delta V_{OUT} - LSB)/LSB$ 

 $\Delta V_{OUT}$  = The measured voltage difference between two adjacent codes

**Offset Error:** The theoretical voltage at the output when the DAC is loaded with all zeros. The output amplifier can have a true negative offset, but because the part is operated from a single supply, the output cannot go below ground. If the offset is negative, the output will remain near OV resulting in the transfer curve shown in Figure 1.

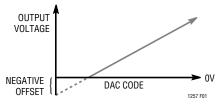


Figure 1. Effect of Negative Offset

The offset of the part is measured at the first code that produces an output voltage 0.5LSB greater than the previous code:

 $V_{OS} = V_{OUT} - [(Code)(V_{FS})/(2^n - 1)]$ 

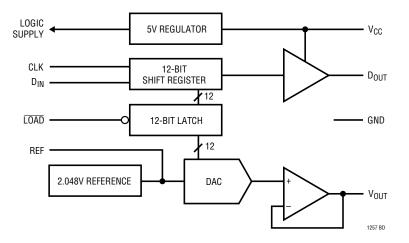
**Full-Scale Error:** Full-scale error is the difference between the ideal and measured DAC output voltages with all bits set to one (Code = 4095). The full-scale error includes the offset error and is calculated as follows:

**Gain Error:** Gain error is the difference between the ideal and measured slope of the DAC transfer characteristic. Gain error is equal to full-scale error minus offset error.

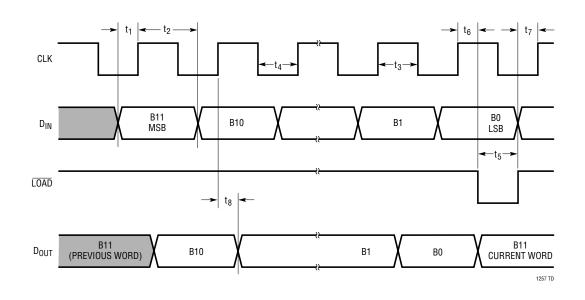
**Digital Feedthrough:** The glitch that appears at the analog output caused by AC coupling from the digital inputs when they change state. The area of the glitch is specified in (nV)(sec).



## **BLOCK DIAGRAM**



## TIMING DIAGRAM





# OPERATION

### Serial Interface

The data on the  $D_{IN}$  input is loaded into the shift register on the rising edge of the clock. The MSB is loaded first and the LSB last. The DAC register loads the data from the shift register when  $\overline{LOAD}$  is pulled low, and remains transparent until  $\overline{LOAD}$  is pulled high and the data is latched.

An internal 5V regulator provides the supply for the digital logic. By limiting the internal digital signal swings to 5V, digital noise is reduced. The buffered output of the 12-bit shift register is available on the  $D_{OUT}$  pin which will swing from GND to  $V_{CC}$ .

Multiple LTC1257s may be daisy chained together by connecting the  $D_{OUT}$  pin to the  $D_{IN}$  pin of the next chip, while the clock and load signals remain common to all chips in the daisy chain. The serial data is clocked to all of the chips, then the LOAD signal is pulled low to update all of them simultaneously. The maximum clocking rate is 1.4MHz.

#### Reference

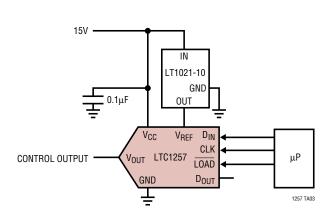
The LTC1257 includes an internal 2.048V reference, making 1LSB equal to  $500\mu$ V. The internal reference output is turned off when the pin is forced above the reference voltage, allowing an external reference to be connected to the reference pin. The external reference must be greater than 2.475V and less than V<sub>CC</sub> – 2.7V, and be capable of driving the 10k minimum DAC resistor ladder.

If the reference output is driving a large capacitive load, a series resistor must be added to insure stability. For any capacitive load greater than  $1\mu F, a\,10\Omega$  series resistor will suffice.

### Voltage Output

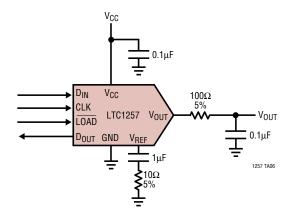
The LTC1257 voltage output is able to pull within 2.7V of  $V_{CC}$  while sourcing 2mA. A internal NMOS transistor with a 200 $\Omega$  equivalent impedance pulls the output to ground. The output is protected against short circuits and is able to drive up to a 500pF capacitive load without oscillation. If digital noise on the output causes a problem, a simple 100 $\Omega$ , 0.1µF RC circuit can be used to filter the noise.

## TYPICAL APPLICATIONS



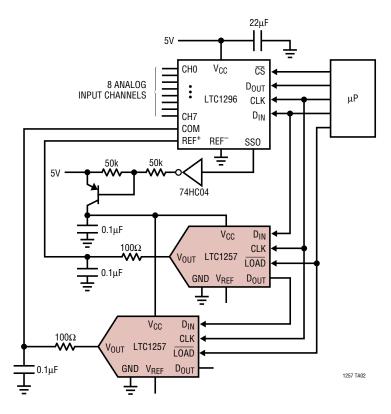
**DAC with External Reference** 

Filtering V<sub>REF</sub> and V<sub>OUT</sub>



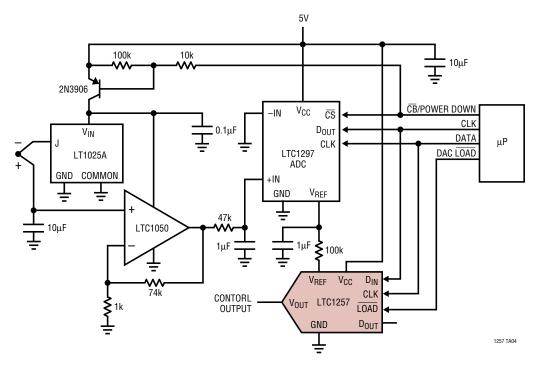


### **TYPICAL APPLICATIONS**



#### Auto Ranging 8-Channel ADC with Shutdown

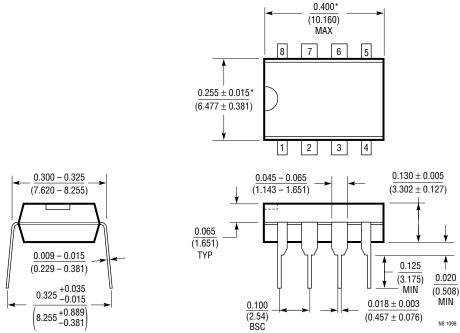






# PACKAGE DESCRIPTION

N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510)

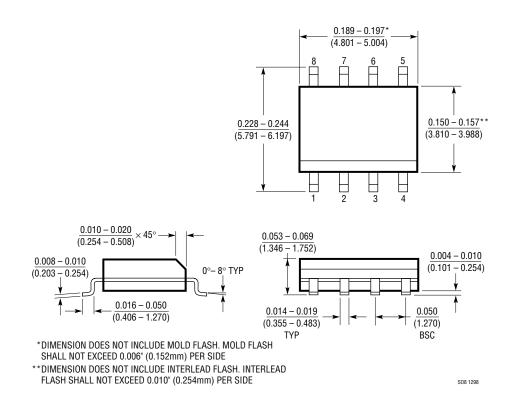


\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)



### PACKAGE DESCRIPTION

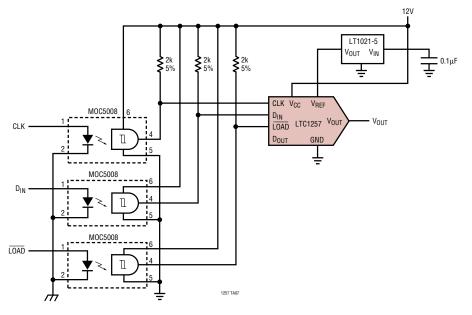
S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)





Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

## TYPICAL APPLICATION



#### Driving LTC1257 with Optoisolators

### **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS				
12 Bit						
LTC1446/LTC1446L	Dual 12-Bit V <sub>OUT</sub> DACs in SO-8 Package	LTC1446: $V_{CC} = 4.5V$ to 5.5V, $V_{OUT} = 0V$ to 4.095V LTC1446L: $V_{CC} = 2.7V$ to 5.5V, $V_{OUT} = 0V$ to 2.5V				
LTC1448	Dual 12-Bit $V_{\mbox{OUT}}$ DAC in SO-8 Package, $V_{\mbox{CC}}$ : 2.7V to 5.5V	Output Swings from GND to REF, REF Input Can Be Tied to V <sub>CC</sub>				
LTC1450/LTC1450L	Single 12-Bit V <sub>OUT</sub> DACs with Parallel Interface	LTC1450: $V_{CC}$ = 4.5V to 5.5V, $V_{OUT}$ = 0V to 4.095V LTC1450L: $V_{CC}$ = 2.7V to 5.5V, $V_{OUT}$ = 0V to 2.5V				
LTC1451	Single Rail-to-Rail 12-Bit V <sub>OUT</sub> DAC, Full Scale: 4.095V, V <sub>CC</sub> : 4.5V to 5.5V, Internal 2.048V Reference Brought Out to Pin	Low Power, Complete V <sub>OUT</sub> DAC in SO-8 Packag				
LTC1452	Single Rail-to-Rail 12-Bit $V_{\text{OUT}}$ Multiplying DAC, $V_{\text{CC}}$ : 2.7V to 5.5V	Low Power, Multiplying V <sub>OUT</sub> DAC with Rail-to-Rail Buffer Amplifier in SO-8 Package				
LTC1453	Single Rail-to-Rail 12-Bit V <sub>OUT</sub> DAC, Full Scale: 2.5V, V <sub>CC</sub> : 2.7V to 5.5V	3V, Low Power, Complete V <sub>OUT</sub> DAC in SO-8 Package				
LTC1454/LTC1454L	Dual 12-Bit $V_{OUT}$ DACs in SO-16 Package with Added Functionality	LTC1454: $V_{CC} = 4.5V$ to 5.5V, $V_{OUT} = 0V$ to 4.095V LTC1454L: $V_{CC} = 2.7V$ to 5.5V, $V_{OUT} = 0V$ to 2.5V				
LTC1456	Single Rail-to-Rail Output 12-Bit DAC with Clear Pin, Full Scale: 4.095V, V <sub>CC</sub> : 4.5V to 5.5V	Low Power, Complete V <sub>OUT</sub> DAC in SO-8 Package with Clear Pin				
LTC1458/LTC1458L	Quad 12 Bit Rail-to-Rail Output DACs with Added Functionality	LTC1458: $V_{CC} = 4.5V$ to 5.5V, $V_{OUT} = 0V$ to 4.095V LTC1458L: $V_{CC} = 2.7V$ to 5.5V, $V_{OUT} = 0V$ to 2.5V				
LTC1659	Single Rail-to-Rail 12-Bit $V_{OUT}$ DAC in MSOP-8 Package, $V_{CC} = 2.7V$ to 5.5V	Output Swings from GND to REF, REF Input Can Be Tied to V <sub>CC</sub>				
14 Bit		-				
LTC1658	14-Bit Rail-to-Rail Micropower DAC in MSOP, $V_{CC}$ = 2.7V to 5.5V	Output Swings from GND to REF, REF Input Can Be Tied to V <sub>CC</sub>				
LTC1654	Dual 14-Bit V <sub>OUT</sub> DAC	Programmable Speed/Power, SO-8 Footprint				
16 Bit	•					
LTC1655(L)	Single 16-Bit V <sub>OUT</sub> DAC with Serial Interface in SO-8	$V_{CC} = 5V (3V)$ , Low Power, Deglitched, $V_{OUT} = 0V \text{ to } 4.096V (0V \text{ to } 2.5V)$				